

Low Power Dual Operational Amplifier

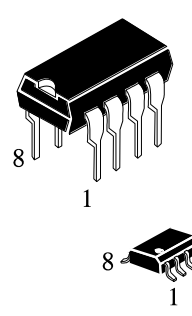
IL2904

The IL2904 contains two independent high gain operational amplifiers with internal frequency compensation. The two op-amps operate over a wide voltage range from a single power supply. Also use a split power supply. The device has low power supply current drain, regardless of the power supply voltage. The low power drain also makes the IL2904 a good choice for battery operation.

When your project calls for a traditional op-amp function, now you can streamline your design with a simple single power supply. Use ordinary +5VDC common to practically any digital system or personal computer application, without requiring an extra 15V power supply just to have the interface electronics you need.

The IL2904 is a versatile, rugged workhorse with a thousand-and-one uses, from amplifying signals from a variety of transducers to dc gain blocks, or any op-amp function. The attached pages offer some recipes that will have your project cooking in no time.

- Internally frequency compensated for unity gain
- Large DC voltage gain: 100dB
- Wide power supply range:
3V ~ 32V (or ±1.5V ~ ±16V)
- Input common-mode voltage range includes ground
- Large output voltage swing: 0V DC to $V_{CC}-1.5V$ DC
- Power drain suitable for battery operation
- Low input offset voltage and offset current
- Differential input voltage range equal to the power supply voltage
- Possible to exchange the position of Pin9 for Pin1 because of Pin Connection being symmetric (IL2904S only)

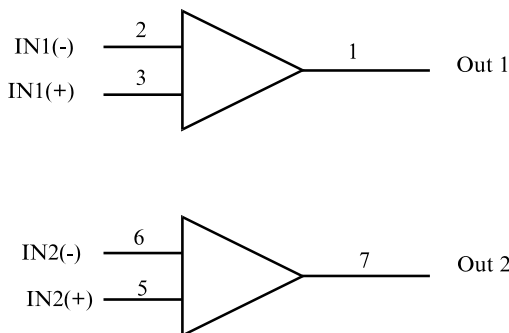


N SUFFIX
PLASTIC

D SUFFIX
SOIC

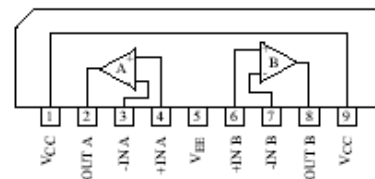
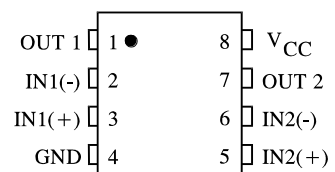
ORDERING INFORMATION
 IL2904N Plastic
 IL2904D SOIC
 $T_A = -40^\circ$ to 105° C
 for all packages.

LOGIC DIAGRAM



PIN 4 = GND
PIN 8 = V_{CC}

PIN ASSIGNMENT



MAXIMUM RATINGS*

Symbol	Parameter	Value	Unit
V_{CC}	Power Supply Voltages		
	Single Supply Split Supplies	32 ±16	V
V_{IDR}	Input Differential Voltage Range (1)	±32	V
V_{ICR}	Input Common Mode Voltage Range	-0.3 to 32	V
I_{SC}	Output Short Circuit Duration	Continuous	
T_J	Junction Temperature		
	Plastic Packages	150	°C
T_{stg}	Storage Temperature		
	Plastic Packages	-55 to +125	°C
I_{IN}	Input Current, per pin (2)	50	mA
T_L	Lead Temperature, 1mm from Case for 10 Seconds	260	°C

* Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Functional operation should be restricted to the Recommended Operating Conditions.

+Derating - Plastic DIP: - 10 mW/°C from 65° to 125°C

SOIC Package: - 7 mW/°C from 65° to 125°C

Notes:

1. Split Power Supplies.
2. $V_{IN} < -0.3V$. This input current will only exist when voltage at any of the input leads is driven negative.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V_{CC}	DC Supply Voltage	±2.5 or 5.0	±15 or 30	V
T_A	Operating Temperature, All Package Types	-40	+105	°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation, V_{IN} and V_{OUT} should be constrained to the range $GND \leq (V_{IN} \text{ or } V_{OUT}) \leq V_{CC}$.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

DC ELECTRICAL CHARACTERISTICS ($T_A=-40$ to $+105^{\circ}\text{C}$)

Symbol	Parameter	Test Conditions	Guaranteed Limit			Unit
			Min	Typ	Max	
V_{IO}	Maximum Input Offset Voltage	$V_O=1.4\text{V}$ $V_{CC}=5.0\text{-}30\text{V}$; $R_S=0\Omega$ $V_{ICM}=0\text{V}$ to $V_{CC}-1.7\text{V}$			9.0 5.0*	mV
$\Delta V_{IO}/\Delta T$	Input Offset Voltage Drift	$R_S=0\Omega$, $V_{CC}=30\text{V}$		7.0		$\mu\text{V}/^{\circ}\text{C}$
I_{IO}	Maximum Input Offset Current	$V_{CC}=5.0\text{V}$			150 50*	nA
$\Delta I_{IO}/\Delta T$	Input Offset Current Drift	$R_S=0\Omega$, $V_{CC}=30\text{V}$		10		$\text{pA}/^{\circ}\text{C}$
I_{IB}	Maximum Input Bias Current	$V_{CC}=5.0\text{V}$			500 250*	nA
V_{ICR}	Input Common Mode Voltage Range	$V_{CC}=30\text{V}$	0		28	V
I_{CC}	Maximum Power Supply Current	$R_L=\infty$, $V_{CC}=30\text{V}$, $V_O=0\text{V}$ $R_L=\infty$, $V_{CC}=5\text{V}$, $V_O=0\text{V}$			3 1.2	mA
A_{VOL}	Minimum Large Signal Open-Loop Voltage Gain	$V_{CC}=15\text{V}$, $R_L \geq 2\text{K}\Omega$	15 25*			V/mV
V_{OH}	Minimum Output High-Level Voltage Swing	$V_{CC}=30\text{V}$, $R_L=2\text{K}\Omega$ $V_{CC}=30\text{V}$, $R_L=10\text{K}\Omega$	26 27			V
V_{OL}	Maximum Output Low-Level Voltage Swing	$V_{CC}=5\text{V}$, $R_L=10\text{K}\Omega$			20	mV
CMR	Common Mode Rejection	$V_{CC}=30\text{V}$, $R_S=10\text{K}\Omega$	65*			dB
PSR	Power Supply Rejection	$V_{CC}=30\text{V}$	65*			dB
CS	Channel Separation	$f=1\text{KHz}$ to 20KHz , $V_{CC}=30\text{V}$	-120*			dB
I_{SC}	Maximum Output Short Circuit to GND	$V_{CC}=5.0\text{V}$ $V_O=0\text{V}$			60*	mA
I_{source}	Minimum Source Output Current	$V_{IN+}=1\text{V}$, $V_{IN-}=0\text{V}$, $V_{CC}=15\text{V}$, $V_O=2\text{V}$	10			mA
I_{sink}	Minimum Output Sink Current	$V_{IN+}=0\text{V}$, $V_{IN-}=1\text{V}$, $V_{CC}=15\text{V}$, $V_O=15\text{V}$ $V_{IN+}=0\text{V}$, $V_{IN-}=1\text{V}$, $V_{CC}=15\text{V}$, $V_O=0.2\text{V}$	5 10* 12*			mA μA
V_{IDR}	Differential Input Voltage Range	All $V_{IN} \geq \text{GND}$ or V-Supply (if used)			V_{CC}^*	V

*= $@25^{\circ}\text{C}$

TYPICAL PERFORMANCE CHARACTERISTICS

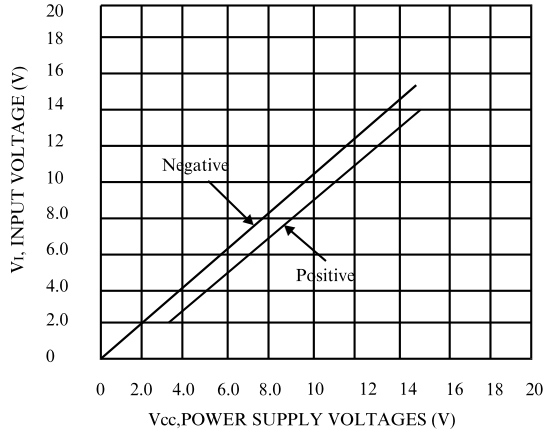


Figure 1. Input Voltage Range

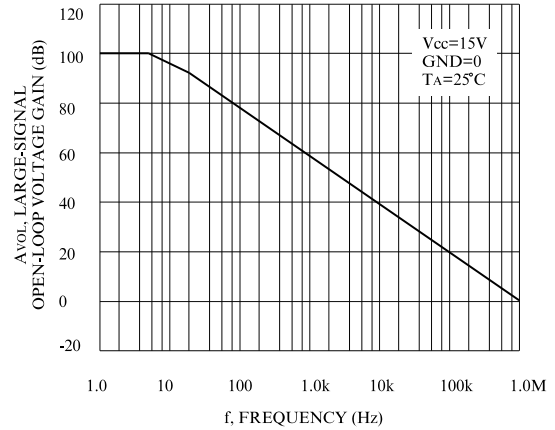


Figure 2. Open-Loop Frequency

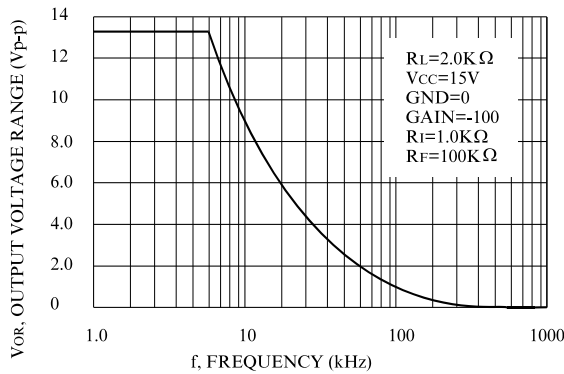


Figure 3. Large-Signal Frequency Response

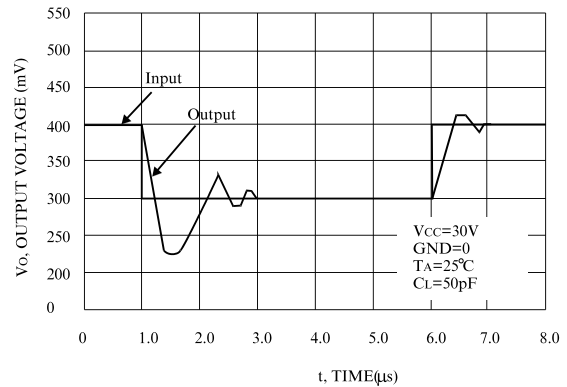


Figure 4. Small-Signal Voltage Follower Pulse Response (Noninverting)

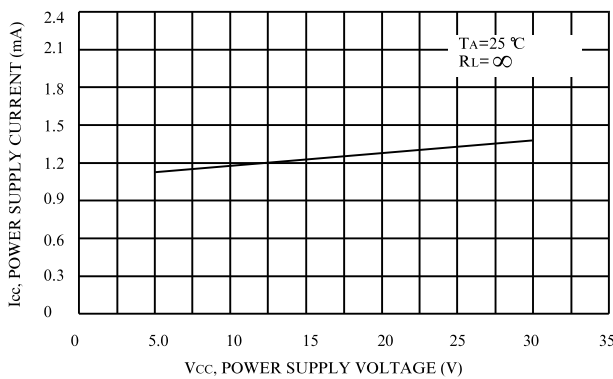


Figure 5. Power Supply Current versus Power Supply Voltage

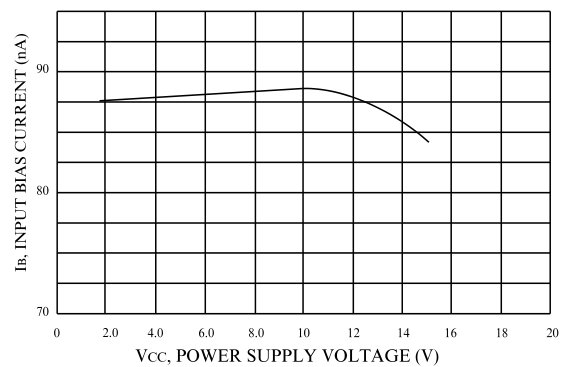
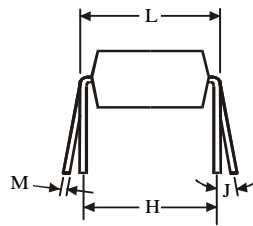
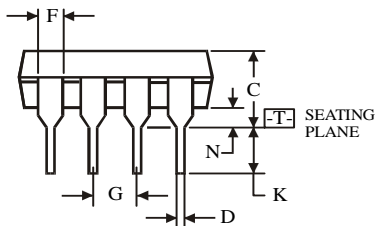
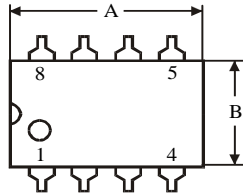
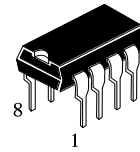


Figure 6. Input Bias Current versus Power Supply Voltage

PACKAGE DIMENSIONS

N SUFFIX PLASTIC DIP
(MS - 001BA)



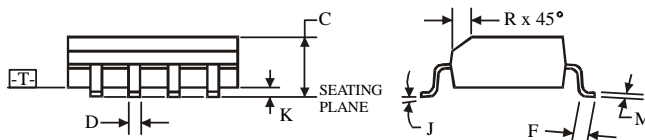
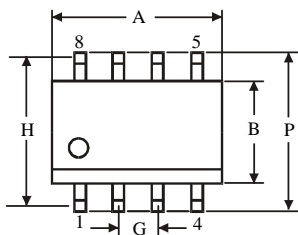
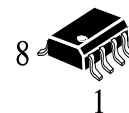
$\oplus 0.25 (0.010) \text{ (M) T}$

Symbol	Dimension, mm	
	MIN	MAX
A	8.51	10.16
B	6.1	7.11
C		5.33
D	0.36	0.56
F	1.14	1.78
G	2.54	
H	7.62	
J	0°	10°
K	2.92	3.81
L	7.62	8.26
M	0.2	0.36
N	0.38	

NOTES:

- Dimensions "A", "B" do not include mold flash or protrusions.
Maximum mold flash or protrusions 0.25 mm (0.010) per side.

D SUFFIX SOIC
(MS - 012AA)



$\oplus 0.25 (0.010) \text{ (M) T C (M)}$

Symbol	Dimension, mm	
	MIN	MAX
A	4.8	5
B	3.8	4
C	1.35	1.75
D	0.33	0.51
F	0.4	1.27
G	1.27	
H	5.72	
J	0°	8°
K	0.1	0.25
M	0.19	0.25
P	5.8	6.2
R	0.25	0.5

NOTES:

- Dimensions A and B do not include mold flash or protrusion.
- Maximum mold flash or protrusion 0.15 mm (0.006) per side for A; for B - 0.25 mm (0.010) per side.